

**Vishay Siliconix** 

## High-Speed Quad Monolithic SPST CMOS Analog Switch

## DESCRIPTION

The DG271B high speed quad single-pole single-throw analog switch is intended for applications that require low on-resistance, low leakage currents, and fast switching speeds.

Built on the Vishay Siliconix' proprietary high voltage silicon gate process to achieve superior on/off performance, each switch conducts equally well in both directions when on, and blocks up to the supply voltage when off. An epitaxial layer prevents latchup.

The DG271B has a redesign internal regulator which improves start-up over the DG271.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with 100 % matter tin device terminations, the lead (Pb)-free "-E3" suffix is being used as a designator.

### FEATURES

- Fast switching t<sub>ON</sub>: 55 ns
- Low charge injection: 5 pC
- Low r<sub>DS(on)</sub>: 32 Ω
- TTL/CMOS compatible
- Low leakage: 50 pA

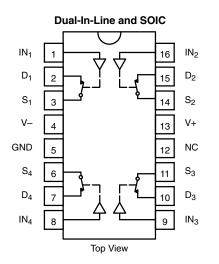
#### **BENEFITS**

- Fast settling times
- Reduced switching glitches
- · High precision

#### **APPLICATIONS**

- High-speed switching
- Sample/hold
- Digital filters
- Op amp gain switching
- Flight control systems
- Automatic test equipment
- Choppers
- · Communication systems

### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE				
Logic	Switch			
0	ON			
1	OFF			

 $\begin{array}{l} \text{Logic "0"} \leq 0.8 \ \text{V} \\ \text{Logic "1"} \geq 2.4 \ \text{V} \end{array}$ 

\* Pb containing terminations are not RoHS compliant, exemptions may apply.



COMPLIANT

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ORDERING INFORMATION				
Temp. Range	Package	Part Number		
0 °C to 70 °C	16-Pin Plastic DIP	DG271BCJ-E3		
- 40 °C to 85 °C	16-Pin Narrow SOIC	DG271BDY-E3		
	To-Fill Nation SOIC	DG271BDY-T1-E3 (with Tape and Reel)		

Parameter		Limit	Unit		
V+ to V-		44			
GND to V-		25	v		
Digital Inputs <sup>a</sup> V <sub>S</sub> , V <sub>D</sub>		(V-) - 2 to (V+) + 2 or 20 mA, whichever occurs first			
Current, Any Terminal		30	— mA		
Peak Current, S or D (Pulsed at 1	ms, 10 % duty cycle max.)	100			
Storage Temperature	(DY Suffix)	- 65 to 150	°C		
Storage Temperature	(CJ Suffix)	- 65 to 125			
Devuer Dissingtion (Declars) <sup>b</sup>	16-Pin Plastic DIP <sup>c</sup>	470	mW		
Power Dissipation (Package) <sup>b</sup>	16-Pin Plastic Narrow SOIC <sup>d</sup>	600			

Notes:

a. Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC board.

c. Derate 6.5 mW/°C above 75 °C.

d. Derate 7.6 mW/°C above 75 °C.



		Test Conditions Unless Specified V+ = 15 V, V- = - 15 V		<b>C, D Suffix</b> 0 °C to 70 °C - 40 °C to 85 °C				
Parameter	Symbol	$V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^{\text{f}}$	Temp. <sup>a</sup>	Min. <sup>d</sup>	Typ. <sup>c</sup>	Max. <sup>d</sup>	Uni	
Analog Switch							Į	
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	- 15		15	V	
Drain-Source On-Resistance	r <sub>DS(on)</sub>	I <sub>S</sub> = 1 mA, V <sub>D</sub> = ± 10 V	Room Full		32	50 75	Ω	
Switch Off Leakage Current	I <sub>S(off)</sub>	$V_{D} = \pm 14 \text{ V}, \text{ V}_{S} = \pm 14 \text{ V}$	Room Full	- 1 - 20	± 0.05	1 20	nA	
	I <sub>D(off)</sub>	$v_{\rm D} = \pm 14 v, v_{\rm S} = \pm 14 v$	Room Full	- 1 - 20	± 0.05	1 20		
Channel On Leakage Current	I <sub>D(on)</sub> + I <sub>S(on)</sub>	$V_{S} = V_{D} = 14 V$	Room Full	- 1 - 20	± 0.05	1 20		
Digital Control					•			
Input Current with Voltage High	I <sub>INH</sub>	V <sub>IN</sub> = 2 V	Full	- 1	0.010	1	μΑ	
		V <sub>IN</sub> = 15 V	Full	- 1	0.010	1		
Input Current with Voltage Low	I <sub>INL</sub>	V <sub>IN</sub> = 0 V	Full	- 1	0.010	1		
Dynamic Characteristics							-	
Turn-On Time	t <sub>ON</sub>	V <sub>S</sub> = ± 10 V	Room Full		55	65 80	ne	
Turn-Off Time	t <sub>OFF</sub>	See Figure 3	Room Full		50	65 80	ns	
Charge Injection	Q	$C_L = 1 \text{ nF}, V_S = 0 \text{ V}, V_{gen} = 0 \text{ V}, R_{gen} = 0 \Omega$ See Figure 3	Room		- 5		pC	
Source-Off Capacitance	C <sub>S(off)</sub>	V <sub>S</sub> = 0 V, V <sub>IN</sub> = 5 V	Room		8			
Drain-Off Capacitance	C <sub>D(off)</sub>	f = 1 MHz	Room		8		pF	
Channel On Capacitance	C <sub>D(on)</sub>	$V_{\rm D} = V_{\rm S} = 0 \text{ V}, V_{\rm IN} = 0 \text{ V}$	Room		30			
Off-Isolation	OIRR	$C_L = 10 \text{ pF}, \text{ R}_L = 1 \text{ k}\Omega$	Room		85		dB	
Crosstalk	X <sub>TALK</sub>	f = 100 kHz, See Figures 4 and 5	Room		100			
Power Supply								
Positive Supply Current	l+	All Channels On or Off	Room Full		5.5	7.5 9	mA	
Negative Supply Current	I-	V <sub>IN</sub> = 5 V or 0 V	Room Full	- 6 - 8	- 3.4		11174	

Notes :

a. Refer to PROCESS OPTION FLOWCHART.

b. Room = 25  $^{\circ}$ C, Full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

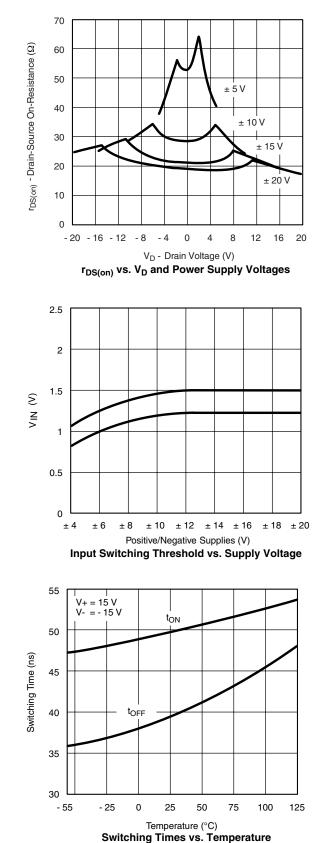
e. Guaranteed by design, not subject to production test.

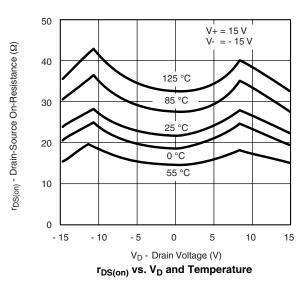
f.  $V_{IN}$  = input voltage to perform proper function.

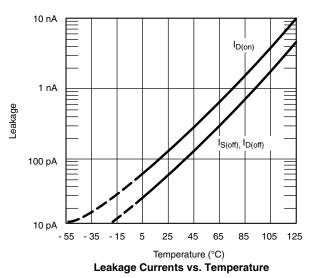
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

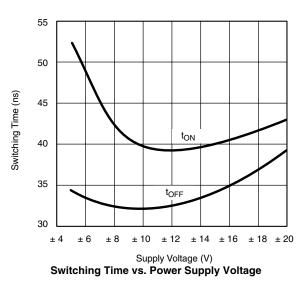
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## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted











DG271B Vishay Siliconix

## SCHEMATIC DIAGRAM Typical Channel

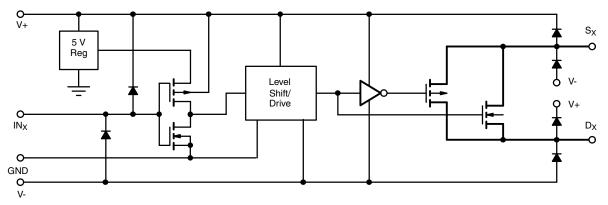
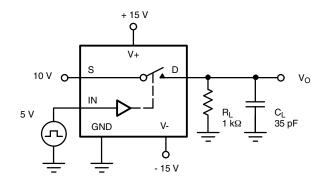
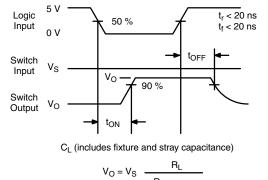




Figure 2. Switching Time

## **TEST CIRCUITS**





R<sub>L</sub> + r<sub>DS(on)</sub>

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?70966.



SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012







## PDIP: 16-LEAD







	MILLIN	IETERS	INC	HES	
Dim	Min	Max	Min	Max	
Α	3.81	5.08	0.150	0.200	
A <sub>1</sub>	0.38	1.27	0.015	0.050	
В	0.38	0.51	0.015	0.020	
B <sub>1</sub>	0.89	1.65	0.035	0.065	
С	0.20	0.30	0.008	0.012	
D	18.93	21.33	0.745	0.840	
E	7.62	8.26	0.300	0.325	
E <sub>1</sub>	5.59	7.11	0.220	0.280	
<b>e</b> <sub>1</sub>	2.29	2.79	0.090	0.110	
e <sub>A</sub>	7.37	7.87	0.290	0.310	
L	2.79	3.81	0.110	0.150	
Q <sub>1</sub>	1.27	2.03	0.050	0.080	
S	0.38	1.52	.015	0.060	
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482					

# **Application Note 826**

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## **RECOMMENDED MINIMUM PADS FOR SO-16**



Recommended Minimum Pads Dimensions in Inches/(mm)

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